PD -2.470A

International
IOR Rectifier

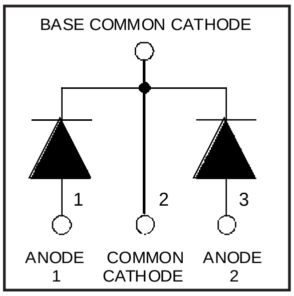
HFA80NK40C

HEXFRED™

Ultrafast, Soft Recovery Diode

Features

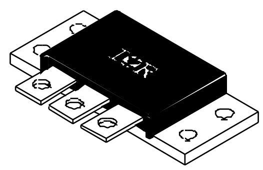
- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters



V_R = 400V
V_F(typ.)③ = 1V
$I_{F(AV)}$ = 80A
Q_{rr} (typ.) = 200nC
I_{RRM}(typ.) = 6A
t_{rr}(typ.) = 30ns
$di_{(rec)M}/dt$ (typ.)③ = 190A/µs

Description

HEXFRED™ diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.



TO-249AA (MODIFIED)

Absolute Maximum Ratings (per Leg)

	Parameter	Max.	Units
V_R	Cathode-to-Anode Voltage	400	V
I_F @ T_C = 25°C	Continuous Forward Current	89	A
I_F @ T_C = 100°C	Continuous Forward Current	44	
I_{FSM}	Single Pulse Forward Current ①	300	
I_{AS}	Maximum Single Pulse Avalanche Current ②	5.0	
E_{AS}	Non-Repetitive Avalanche Energy ②	1.4	mJ
P_D @ T_C = 25°C	Maximum Power Dissipation	160	W
P_D @ T_C = 100°C	Maximum Power Dissipation	63	
T_J T_{STG}	Operating Junction and Storage Temperature Range	-55 to +150	°C
	Soldering Temperature, for 10 sec.	300 (0.063 in. (1.6mm) from case)	

Thermal - Mechanical Characteristics

	Parameter	Min.	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case, Single Leg Conducting	----	----	0.80	°C/W K/W
	Junction-to-Case, Both Legs Conducting	----	----	0.40	
$R_{\theta CS}$	Case-to-Sink, Flat , Greased Surface	----	0.10	----	
Wt	Weight	----	58 (2.0)	----	g (oz)
	Mounting Torque	35 (4.0)	----	50 (5.7)	lbf•in (N•m)

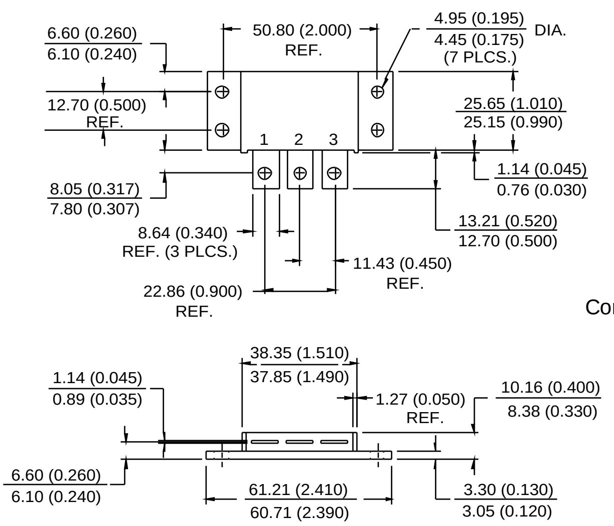
Note: ① Limited by junction temperature
② L = 100µH, duty cycle limited by max T_J
③ 125°C

Electrical Characteristics (per Leg) @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions	
V_{BR}	Cathode Anode Breakdown Voltage	400	–––	–––	V	I_R = 100µA	
V_{FM}	Max Forward Voltage	–––	1.1	1.3	V	I_F = 40A	See Fig. 1
		–––	1.3	1.5		I_F = 80A	
		–––	1.0	1.2		I_F = 40A, T_J = 125°C	
I_{RM}	Max Reverse Leakage Current	–––	0.50	3.0	µA	V_R = V_R Rated	See Fig. 2
		–––	0.75	4.0	mA	T_J = 125°C, V_R = 320V	
C_T	Junction Capacitance	–––	90	125	pF	V_R = 200V	See Fig. 3
L_S	Series Inductance	–––	8.0	–––	nH	From terminal hole to terminal hole	

Dynamic Recovery Characteristics (per Leg) @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions		
t_{rr}	Reverse Recovery Time	–––	30	–––	ns	I_F = 1.0A, di_f/dt = 200A/µs, V_R = 30V		
t_{rr1}		–––	67	100		T_J = 25°C	See Fig.	I_F = 40A
t_{rr2}		–––	110	170		T_J = 125°C	5	
I_{RRM1}	Peak Recovery Current	–––	6.0	11	A	T_J = 25°C	See Fig.	V_R = 200V
I_{RRM2}		–––	9.0	16		T_J = 125°C	6	
Q_{rr1}	Reverse Recovery Charge	–––	200	540	nC	T_J = 25°C	See Fig.	di_f/dt = 200A/µs
Q_{rr2}		–––	500	1300		T_J = 125°C	7	
$di_{(rec)M}/dt1$	Peak Rate of Fall of Recovery Current	–––	240	–––	A/µs	T_J = 25°C	See Fig.	
$di_{(rec)M}/dt2$	During t_b	–––	190	–––		T_J = 125°C	8	



LEAD ASSIGNMENTS
- 1 - ANODE
- 2 - CATHODE
- 3 - ANODE
- BASE COMMON CATHODE

Conforms to JEDEC Outline TO - 249AA (Modified)
Dimensions in millimeters and inches

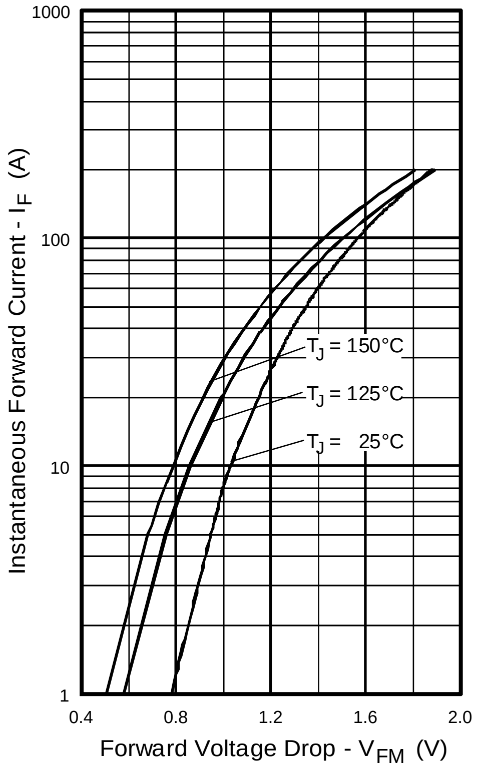


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current, (per Leg)

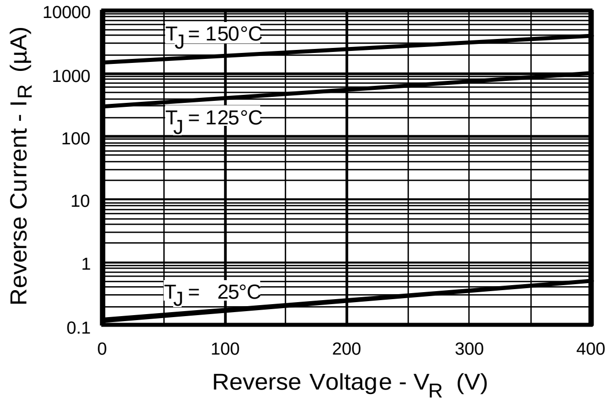


Fig. 2 - Typical Reverse Current vs. Reverse Voltage, (per Leg)

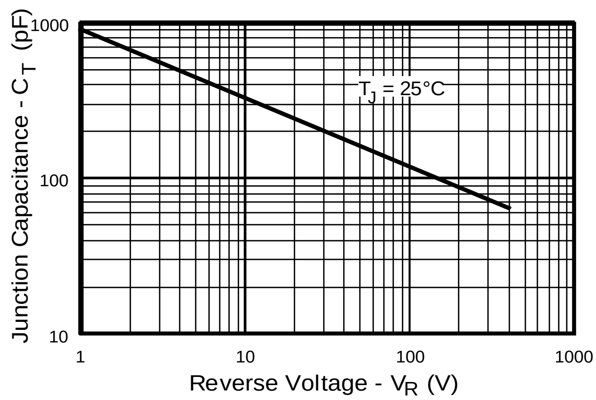


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, (per Leg)

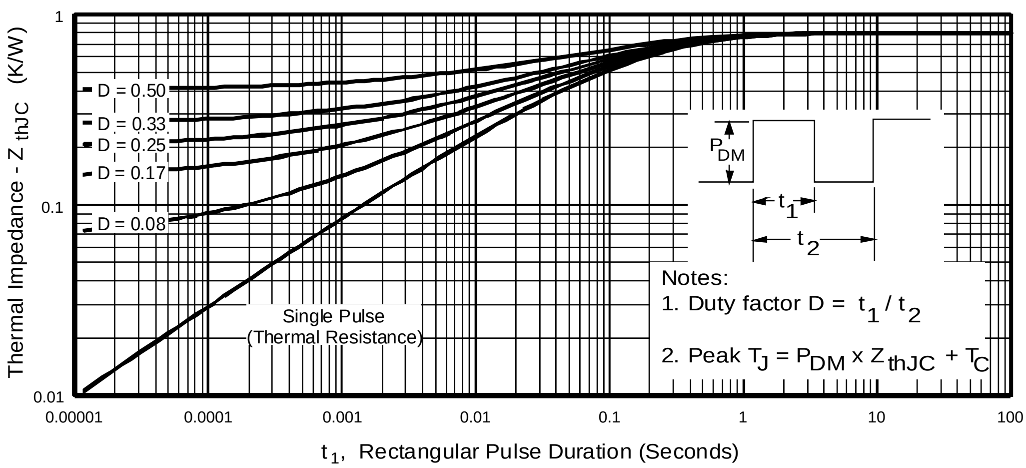


Fig. 4 - Maximum Thermal Impedance Z_{thjc} Characteristics, (per Leg)

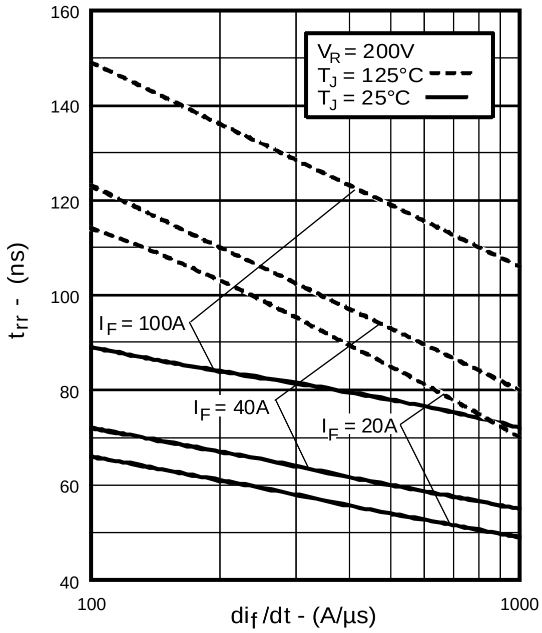


Fig. 5 - Typical Reverse Recovery vs. di_f/dt, (per Leg)

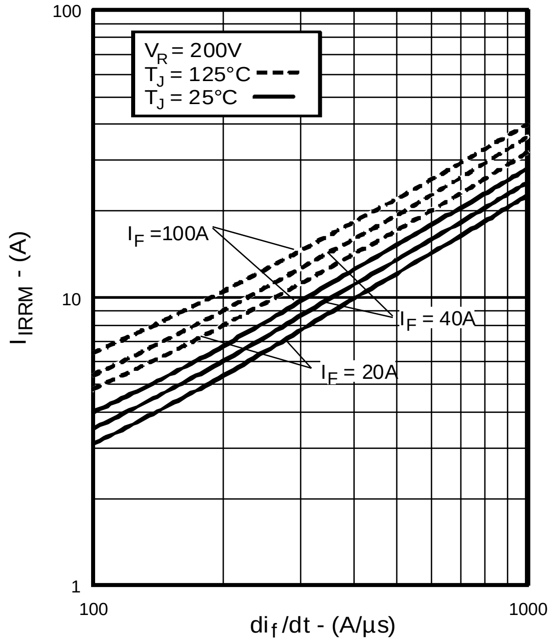


Fig. 6 - Typical Recovery Current vs. di_f/dt, (per Leg)

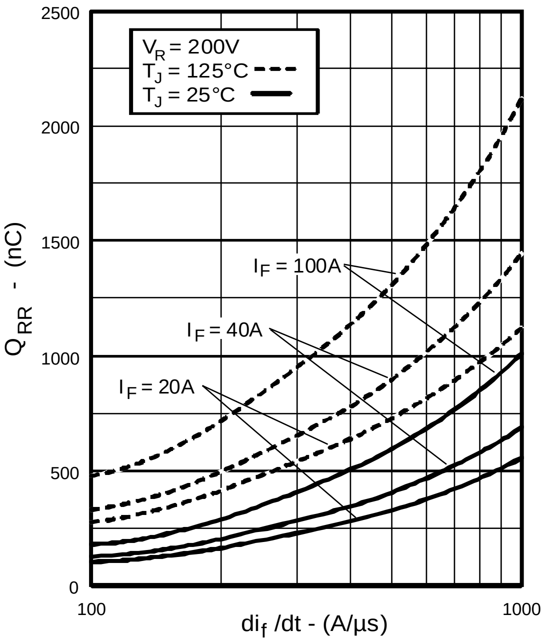


Fig. 7 - Typical Stored Charge vs. di_f/dt, (per Leg)

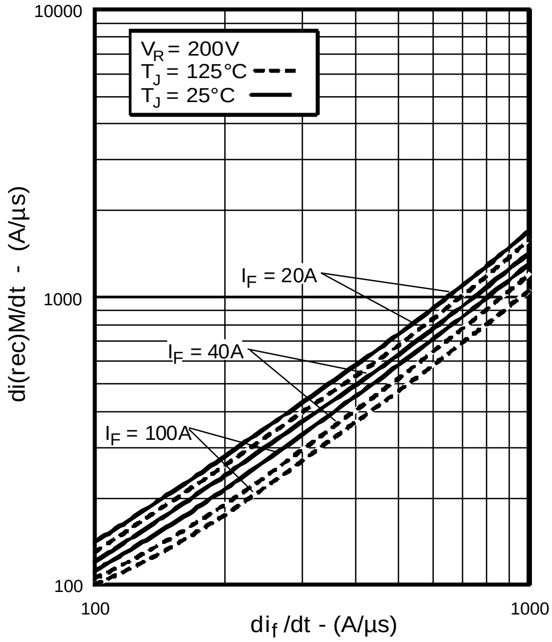


Fig. 8 - Typical $di_{(rec)M}/dt$ vs. di_f/dt, (per Leg)

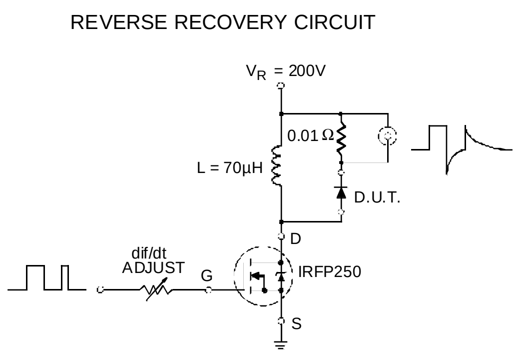
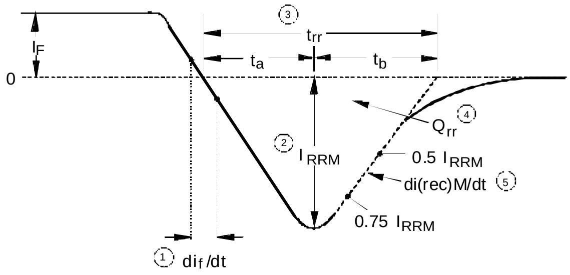


Fig. 9 - Reverse Recovery Parameter Test Circuit



1. di_f/dt - Rate of change of current through zero crossing
2. I_{RRM} - Peak reverse recovery current
3. trr - Reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current
4. Q_{rr} - Area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

5. $di_{(rec)M}/dt$ - Peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

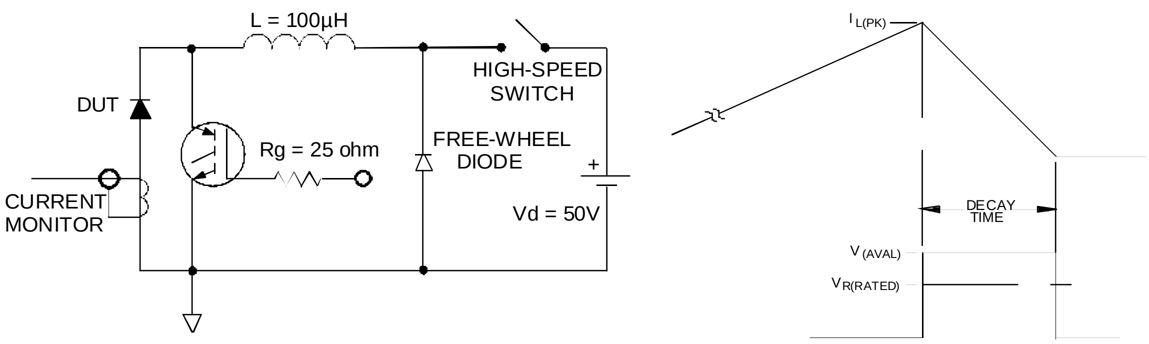


Fig. 11 - Avalanche Test Circuit and Waveforms

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